

Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

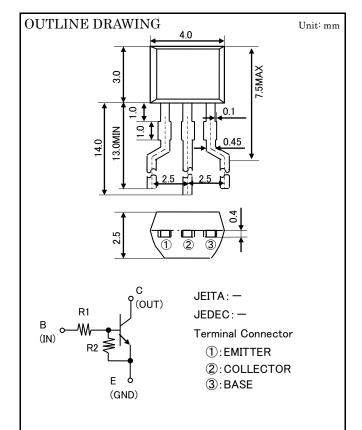
DESCRIPTION RT1N137S is a one chip transistor with built-in bias resistor, PNP type is RT1P137S.

## FEATURE

 $\begin{array}{ll} \mbox{Built-in bias resistor} & (R_1 = 1 k \, \Omega \,, \, R_2 = 22 k \, \Omega \,) \\ \mbox{High collector current} & (I_C = 1 A) \\ \mbox{Low V}_{CE(sat)} & V_{CE(sat)} = 0.3 V \\ & (@I_C = 300 m A/I_B = 3 m A) \end{array}$ 

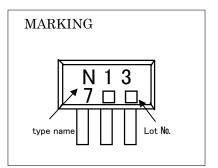
### APPLICATION

Inverted circuit, Switching circuit, Interface circuit, Driver circuit



## MAXIMUM RATING (Ta=25°C)

-				
SYMBOL	PARAMETER RATING		UNIT	
Vcbo	Collector to Base voltage	40	V	
$V_{\rm EBO}$	Emitter to Base voltage	er to Base voltage 6		
Vceo	Collector to Emitter voltage	40	V	
Ic	Collector current	1	А	
$I_{\rm CM}$	Peak Collector current	2	А	
Pc	Collector dissipation	600	mW	
$T_{j}$	Junction temperature	+150	°C	
$\mathrm{T}_{\mathrm{stg}}$	Storage temperature	-55~+150	°C	



## ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	UNII
V(BR)CEO	C to E breakdown voltage	I <sub>C</sub> =1mA, $R_{BE}=\infty$	40			V
Ісво	Collector cut off current	V <sub>CB</sub> =40V, I <sub>E</sub> =0	-	-	0.1	μA
Iebo	Emitter cut off current	$V_{EB}=5V$ , $I_C=0$	168	217	310	μA
$\mathbf{h}_{\mathrm{FE}}$	DC forward current gain	V <sub>CE</sub> =6V, I <sub>C</sub> =100mA	100	-	-	—
VCE(sat)	C to E saturation voltage	Ic=300mA, IB=3mA		0.1	0.3	V
VI(ON)	Input on voltage	V <sub>CE</sub> =0.2V, I <sub>C</sub> =300mA	-	2.3	4.0	V
VI(OFF)	Input off voltage	V <sub>CE</sub> =5V, I <sub>C</sub> =100 $\mu$ A	0.4	0.5	-	V
$R_1$	Input resistor	-	0.7	1.0	1.3	kΩ
$R_2 \swarrow R_1$	Resistor ratio	-	20	22	24	—
$\mathbf{f}_{\mathrm{T}}$	Gain band width product	V <sub>CE</sub> =6V, I <sub>E</sub> =-10mA		150	_	MHz

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**RT1N137S** 

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DC FORWARD CURRENT GAIN

VS. COLLECTOR CURRENT

VCE=5V

10

VCE=5V

0.2

0.4

100

0.8

1.0

0.6

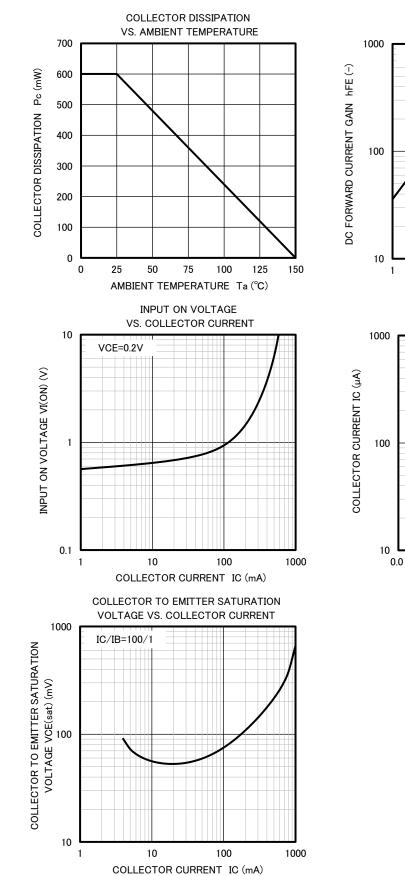
INPUT OFF VOLTAGE VI(OFF) (V)

COLLECTOR CURRENT IC (mA)

COLLECTOR CURRENT

VS. INPUT OFF VOLTAGE

1000



### TYPICAL CHARACTERISTICS(Ta=25°C)

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